EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

Amendments to the Claims:

Please amend claims 2-9, 11-20, 47-52, and 54-61 as set forth below. Please cancel claims 1, 10, 46, and 53. Following is a complete listing of the claims pending in the application, as amended:

1. (Cancelled)

- 2. (Currently amended) The method of claim 87 4—wherein the radiation includes a beam having a beam width at the microlithographic substrate, and wherein moving the microlithographic substrate includes oscillating the microlithographic substrate toward and away from the reticle along an axis generally parallel to the substrate radiation path segment, further wherein a motion of the microlithographic substrate is periodic and wherein moving the microlithographic substrate includes moving the microlithographic substrate for one period during the time the microlithographic substrate moves transverse to the beam by a distance of one beam width or about one beam width.
- 3. (Currently amended) The method of claim 87 4—wherein the radiation includes a beam having a beam width at least proximate to an intersection between the beam and the microlithographic substrate, and wherein moving the microlithographic substrate includes oscillating the microlithographic substrate toward and away from the reticle along an axis generally parallel to the substrate radiation path segment, further wherein a motion of the microlithographic substrate is periodic and wherein moving the microlithographic substrate includes moving the microlithographic substrate for an integer number of periods during the time the microlithographic substrate moves transverse to the beam by a distance of one beam width or about one beam width.
- 4. (Currently amended) The method of claim <u>87</u> **1**-wherein moving the reticle includes moving the reticle along a reticle path generally normal to the reticle radiation path segment at least proximate to a point where the radiation impinges on the reticle.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

5. (Currently amended) The method of claim 87 1—wherein moving the

microlithographic substrate includes moving the microlithographic substrate along a

substrate path having a first component generally parallel to the substrate radiation path

segment of the radiation at least proximate to a point where the radiation strikes the

microlithographic substrate, the substrate path having a second component generally

perpendicular to the substrate radiation path segment at least proximate to a point

where the radiation strikes the microlithographic substrate.

6. (Currently amended) The method of claim 874, further comprising

selecting the radiation-sensitive material to include a coating of photoresist material.

7. (Currently amended) The method of claim 874, further comprising

selecting the radiation to have a wavelength of from about 13 nanometers or less to

about 365 nanometers.

8. (Currently amended) The method of claim 874, further comprising

orienting a plane of the reticle approximately normal to the first direction.

9. (Currently amended) The method of claim 87 4—wherein moving the

microlithographic substrate includes simultaneously moving the microlithographic

substrate parallel to and perpendicular to the second direction.

10. (Cancelled)

11. (Currently amended) The method of claim 87 4-wherein moving the reticle

includes moving the reticle in a direction opposite to the second component of motion of

the microlithographic substrate.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

12. (Currently amended) The method of claim <u>87</u> **1**—wherein moving the microlithographic substrate includes moving the microlithographic substrate along a curved path.

- 13. (Currently amended) The method of claim <u>87</u> **1**—wherein moving the microlithographic substrate includes moving the microlithographic substrate along a straight path having a first segment directed toward the reticle and a second segment directed away from the reticle.
- 14. (Currently amended) The method of claim <u>87</u> 4—wherein moving the microlithographic substrate includes moving the microlithographic substrate along a path describing a square wave.
- 15. (Currently amended) The method of claim <u>87</u> **1**—wherein moving the microlithographic substrate includes moving the microlithographic substrate along a path describing a sinusoidal wave.
- 16. (Currently amended) The method of claim <u>87</u> **1**—wherein moving the microlithographic substrate includes moving the microlithographic substrate along a path that describes a periodic, triangular profile.
- 17. (Currently amended) The method of claim <u>87</u> <u>1</u>—wherein the microlithographic substrate has first and second fields, and wherein the method further comprises:

aligning the radiation path with the first field;

moving the reticle and the microlithographic substrate relative to each other while the radiation path is aligned with the first field;

repositioning at least one of the microlithographic substrate and the radiation path relative to the other to align the radiation path with the second field; and

Attorney Docket No. 108298543US

Disclosure No. 00-1035

moving the reticle and the microlithographic substrate relative to each other while the radiation path is aligned with the second field.

- (Currently amended) The method of claim 874, further comprising 18. selecting the reticle radiation path segment to be approximately parallel to the substrate radiation path segment.
- (Currently amended) The method of claim 87 4-wherein moving the 19. microlithographic substrate includes moving the microlithographic substrate relative to a focal plane of the radiation passing through the reticle.
- 20. (Currently amended) The method of claim 87 4-where a reduction lens is positioned between the reticle and the microlithographic substrate and wherein the method further comprises moving the reduction lens axially relative to the microlithographic substrate to move a focal plane of the radiation axially relative to the microlithographic substrate.
- 21. (Original) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - directing a beam of the radiation along a radiation path in a first direction toward a reticle:
 - passing the radiation through an aperture of the reticle and to the microlithographic substrate along the radiation path in a second direction, the beam having a beam width at least proximate to an intersection between the beam and the microlithographic substrate;

focusing the radiation toward a focal plane;

- moving the reticle relative to the radiation path along a reticle path generally normal to the first direction; and
- moving the microlithographic substrate relative to the radiation path and the focal plane along a substrate path, the substrate path having a first component

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

generally parallel to the second direction, the substrate path having a

second component generally perpendicular to the second direction, the

microlithographic substrate simultaneously moving parallel to and

perpendicular to the second direction while the reticle moves along the

reticle path, and wherein the microlithographic substrate oscillates in a

periodic manner toward and away from the reticle along an axis generally

parallel to the second direction, further wherein moving the

microlithographic substrate includes moving the microlithographic

substrate for an integer number of periods during the time the

microlithographic substrate moves transverse to the beam by a distance of

approximately one beam width.

22. (Original) The method of claim 21 wherein moving the reticle includes

moving the reticle along a reticle path generally normal to the first direction of the

radiation path at least proximate to a point where the radiation impinges on the reticle.

23. (Original) The method of claim 21 wherein moving the microlithographic

substrate includes moving the microlithographic substrate along a substrate path having

a first component generally parallel to the second direction of the radiation at least

proximate to a point where the radiation strikes the microlithographic substrate, the

substrate path having a second component generally perpendicular to the second

direction of the radiation at least proximate to a point where the radiation strikes the

microlithographic substrate.

24. (Original) The method of claim 21, further comprising selecting the

radiation-sensitive material to include a coating of photoresist material.

25. (Original) The method of claim 21, further comprising selecting the

radiation to have a wavelength of from about 13 nanometers or less to about 365

nanometers.

-6-

Attorney Docket No. 108298543US

Disclosure No. 00-1035

26. (Original) The method of claim 21, further comprising orienting a plane of

the reticle approximately normal to the first direction.

27. (Original) The method of claim 21 wherein moving the reticle includes

moving the reticle in a direction opposite to the second component of motion of the

microlithographic substrate.

28. (Original) The method of claim 21 wherein moving the microlithographic

substrate includes moving the microlithographic substrate along a curved path.

29. (Original) The method of claim 21 wherein moving the microlithographic

substrate includes moving the microlithographic substrate along a path describing a

sinusoidal wave.

30. (Original) The method of claim 21 wherein the microlithographic substrate

has first and second fields, and wherein the method further comprises:

aligning the radiation path with the first field;

moving the reticle and the microlithographic substrate relative to each other while

the radiation path is aligned with the first field;

repositioning at least one of the microlithographic substrate and the radiation

path relative to the other to align the radiation path with the second field;

and

moving the reticle and the microlithographic substrate relative to each other while

the radiation path is aligned with the second field.

31. (Original) The method of claim 21, further comprising selecting the first

direction to be approximately parallel to the second direction.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

32-45. (Cancelled)

46. (Cancelled)

- 47. (Currently amended) The apparatus of claim 46-93 wherein the substrate support is coupled to at least one actuator to move simultaneously along both the first and second components of the substrate support path while the reticle moves along the reticle path.
- 48. (Currently amended) The apparatus of claim 46-93 wherein the radiation includes a radiation beam having a beam width proximate to the substrate support surface and wherein the substrate support is coupled to at least one actuator to oscillate in a periodic manner toward and away from the reticle along an axis generally parallel to the second direction, further wherein the substrate support is configured to move for one period during the time the substrate support moves transverse to the beam by a distance of approximately one beam width.
- 49. (Currently amended) The apparatus of claim 46-93 wherein the radiation includes a radiation beam having a beam width proximate to the substrate support surface and wherein the substrate support is configured to oscillate in a periodic manner toward and away from the reticle along an axis generally parallel to the second direction, further wherein the substrate support is configured to move for an integer number of periods during the time the substrate support moves transverse to the beam by a distance of approximately one beam width.
- 50. (Currently amended) The apparatus of claim 46–93 wherein the radiation source is configured to emit radiation having a wavelength of from about 13 nanometers or less to about 365 nanometers.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

51. (Currently amended) The apparatus of claim 46-93 wherein a plane of the

reticle is oriented approximately normal to the first direction.

52. (Currently amended) The apparatus of claim 46–93 wherein the substrate

support is configured to move simultaneously parallel to and perpendicular to the

second direction.

53. (Cancelled)

54. (Currently amended) The apparatus of claim 46-93 wherein the reticle is

coupled to at least one actuator to move in a direction opposite to the second

component of motion of the substrate support.

55. (Currently amended) The apparatus of claim 46-93 wherein the substrate

support is coupled to at least one actuator to move along a curved path.

56. (Currently amended) The apparatus of claim 46-93 wherein the substrate

support is coupled to at least one actuator to move along a straight path having a first

segment directed toward the reticle and a second segment directed away from the

reticle.

57. (Currently amended) The apparatus of claim 46-93 wherein the substrate

support is coupled to at least one actuator to move along a path describing a square

wave.

58. (Currently amended) The apparatus of claim 46–93 wherein the substrate

support is coupled to at least one actuator to move along a path describing a sinusoidal

wave.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

59. (Currently amended) The apparatus of claim 46-93 wherein the substrate support is coupled to at least one actuator to move along a path describing a periodic. triangular profile.

- (Currently amended) The apparatus of claim 46-93 wherein the 60. microlithographic substrate has first and second fields, and wherein the reticle is coupled to at least one actuator to sequentially scan across the first and second fields.
- 61. (Currently amended) The apparatus of claim 46-93 wherein the reticle includes a reticle aperture sized to pass a portion of the radiation toward the microlithographic substrate to form an image on the microlithographic substrate.
- 62. (Original) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a source of radiation positioned to direct a beam of selected radiation along a radiation path;
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path to describe a periodic motion, the beam having a beam width proximate to the substrate support surface;
 - a reticle positioned in the radiation path between the source of radiation and the substrate support to intersect the beam and direct at least a portion of the beam along the radiation path to the substrate support, the reticle being coupled to at least one actuator to move relative to the radiation path in a

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

direction generally perpendicular to the radiation path and opposite the

first component of the substrate support path; and

a controller operatively coupled to the reticle and the substrate support to move

the substrate support for an integer number of periods during the time

required for the microlithographic substrate to move transverse to the

beam by at least one beam width.

63. (Original) The apparatus of claim 62 wherein the radiation source is

configured to emit radiation having a wavelength of from about 13 nanometers or less to

about 365 nanometers.

64. (Original) The apparatus of claim 62 wherein the substrate support is

coupled to at least one actuator to move along a curved path.

65. (Original) The apparatus of claim 62 wherein the substrate support is

coupled to at least one actuator to move along a straight path having a first segment

directed toward the reticle and a second segment directed away from the reticle.

66. (Original) The apparatus of claim 62 wherein the substrate support is

coupled to at least one actuator to move along a path describing a square wave.

67. (Original) The apparatus of claim 62 wherein the substrate support is

coupled to at least one actuator to move along a path describing a sinusoidal wave.

68. (Original) The apparatus of claim 62 wherein the substrate support is

coupled to at least one actuator to move along a path describing a periodic, triangular

profile.

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

69. (Original) The apparatus of claim 62 wherein the reticle includes a reticle aperture sized to pass at least a portion of the radiation beam toward the substrate support to form an image on the microlithographic substrate.

- 70. (Original) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a source of radiation positioned to direct a beam of selected radiation along a radiation path;
 - a substrate support configured to support a microlithographic substrate in the radiation path, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being simultaneously movable along both the first and second components of the substrate support path to describe a periodic motion, the beam having a beam width proximate to the substrate support; and
 - a reticle positioned in the radiation path between the source of radiation and the substrate support to intersect the radiation beam, the reticle including at least one aperture and being positioned to pass the radiation along the radiation path to the substrate support, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path and opposite the first component of the substrate support path; and
 - a controller operatively coupled to the reticle and the substrate support to move the substrate support for an integer number of periods during the time required for the entire width of the beam to pass over a point on the microlithographic substrate.

Attorney Docket No. 108298543US

Disclosure No. 00-1035

71. (Original) The apparatus of claim 70 wherein the radiation source is

configured to emit radiation having a wavelength of from about 13 nanometers or less to

about 365 nanometers.

72. (Original) The apparatus of claim 70 wherein the substrate support is

coupled to at least one actuator to move along a curved path.

73. (Original) The apparatus of claim 70 wherein the substrate support is

coupled to at least one actuator to move along a straight path having a first segment

directed toward the reticle and a second segment directed away from the reticle.

74. (Original) The apparatus of claim 70 wherein the substrate support is

coupled to at least one actuator to move along a path describing a square wave.

75. (Original) The apparatus of claim 70 wherein the substrate support is

coupled to at least one actuator to move along a path describing a sinusoidal wave.

76. (Original) The apparatus of claim 70 wherein the substrate support is

coupled to at least one actuator to move along a path describing a periodic, triangular

profile.

77-84. (Cancelled)

85. (Previously presented) A method for exposing a radiation-sensitive

material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle;

passing the radiation from the reticle and to the microlithographic substrate along

a substrate radiation path segment at the microlithographic substrate, the

radiation including a beam having a beam width at the microlithographic

substrate;

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

moving the reticle along a reticle path generally normal to the reticle radiation path segment; and

moving the microlithographic substrate relative to the radiation path along a substrate path, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate radiation path segment, the microlithographic substrate moving generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path, and wherein the microlithographic substrate oscillates toward and away from the reticle along an axis generally parallel to the substrate radiation path segment, further wherein a motion of the microlithographic substrate is periodic and wherein moving the microlithographic substrate includes moving the microlithographic substrate for one period during the time the microlithographic substrate moves transverse to the beam by a distance of one beam width or about one beam width.

86. (Previously presented) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle;

- passing the radiation from the reticle and to the microlithographic substrate along a substrate radiation path segment at the microlithographic substrate, the radiation including a beam having a beam width at least proximate to an intersection between the beam and the microlithographic substrate;
- moving the reticle along a reticle path generally normal to the reticle radiation path segment; and
- moving the microlithographic substrate relative to the radiation path along a substrate path, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate

Attorney Docket No. 108298543US Disclosure No. 00-1035

radiation path segment, wherein the microlithographic substrate moves generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path, and wherein the microlithographic substrate

oscillates toward and away from the reticle along an axis generally parallel to the substrate radiation path segment, further wherein a motion of the microlithographic substrate is periodic and wherein moving the

microlithographic substrate includes moving the microlithographic substrate for an integer number of periods during the time the

microlithographic substrate moves transverse to the beam by a distance of

one beam width or about one beam width.

87. (Previously presented) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle;

passing the radiation from the reticle and to the microlithographic substrate along a substrate radiation path segment at the microlithographic substrate;

moving the reticle along a reticle path generally normal to the reticle radiation path segment; and

moving the microlithographic substrate relative to the radiation path along a substrate path, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate radiation path segment, wherein the microlithographic substrate moves generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path, and wherein the microlithographic substrate oscillates toward and away from the reticle along a first axis generally parallel to the substrate radiation path segment while the microlithographic substrate simultaneously moves along a second axis generally perpendicular to the substrate radiation path segment.

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

88. (Previously presented) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle;

passing the radiation from the reticle and to the microlithographic substrate along a substrate radiation path segment at the microlithographic substrate;

moving the reticle along a reticle path generally normal to the reticle radiation path segment; and

moving the microlithographic substrate relative to the radiation path along a substrate path describing a square wave, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate radiation path segment, wherein the microlithographic substrate moves generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path.

89. (Previously presented) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle; passing the radiation from the reticle and to the microlithographic substrate along

a substrate radiation path segment at the microlithographic substrate;

moving the reticle along a reticle path generally normal to the reticle radiation path segment; and

moving the microlithographic substrate relative to the radiation path along a substrate path describing a sinusoidal wave, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate radiation path segment, wherein the microlithographic substrate moves generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path.

AREDITED PROCEDURE – Art Unit 2851
Attorney Docket No. 108298543US

Disclosure No. 00-1035

90. (Previously presented) A method for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

directing the radiation along a reticle radiation path segment toward a reticle;

passing the radiation from the reticle and to the microlithographic substrate along a substrate radiation path segment at the microlithographic substrate;

moving the reticle along a reticle path generally normal to the reticle radiation path segment; and

moving the microlithographic substrate relative to the radiation path along a substrate path describing a periodic, triangular profile, the substrate path having a first component generally parallel to the substrate radiation path segment, and the substrate path having a second component generally perpendicular to the substrate radiation path segment, wherein the microlithographic substrate moves generally parallel to and generally perpendicular to the substrate radiation path segment toward and away from the reticle while the reticle moves along the reticle path.

91. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:

a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and

a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, the radiation including a radiation beam having a beam width proximate to the substrate support surface, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path, the substrate support path having a first component generally parallel to the

Attorney Docket No. 108298543US

Disclosure No. 00-1035

radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path while the reticle moves along the reticle path, and wherein the substrate support is coupled to at least one actuator to oscillate in a periodic manner toward and away from the reticle along an axis generally parallel to the second direction, further wherein the substrate support is configured to move for one period during the time the substrate support moves transverse to the beam by a distance of approximately one beam width.

- 92. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, the radiation including a radiation beam having a beam width proximate to the substrate support surface, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate

EXPEDITED PROCEDURE – Art Unit 2851
Attorney Docket No. 108298543US

Attorney Docket No. 108298543US Disclosure No. 00-1035

support path while the reticle moves along the reticle path, and wherein the substrate support is configured to oscillate in a periodic manner toward and away from the reticle along an axis generally parallel to the second direction, further wherein the substrate support is configured to move for an integer number of periods during the time the substrate support moves transverse to the beam by a distance of approximately one beam width.

- 93. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path while the reticle moves along the reticle path, and wherein the substrate support is coupled to at least one actuator to oscillate toward and away from the reticle along a first axis generally parallel to the second direction while moving along a second axis generally perpendicular to the second direction.

EXPEDITED PROCEDURE – Art Unit 2851

Attorney Docket No. 108298543US Disclosure No. 00-1035

- 94. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path describing a square wave, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path while the reticle moves along the reticle path.
- 95. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, wherein the substrate

EXPEDITED PROCEDURE – Art Unit 2851
Attorney Docket No. 108298543US

Disclosure No. 00-1035

support is coupled to at least one actuator to move relative to the radiation path along a substrate support path describing a sinusoidal wave, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path while the reticle moves along the reticle path.

- 96. (Previously presented) An apparatus for exposing a radiation-sensitive material of a microlithographic substrate to a selected radiation, comprising:
 - a radiation source positioned to direct a selected radiation along a radiation path; a reticle positioned in the radiation path, the reticle being configured to selectively direct at least a portion of the radiation toward a microlithographic substrate, the reticle being coupled to at least one actuator to move relative to the radiation path in a direction generally perpendicular to the radiation path; and
 - a substrate support having a support surface positioned to support a microlithographic substrate in the radiation path with the microlithographic substrate receiving radiation from the reticle, wherein the substrate support is coupled to at least one actuator to move relative to the radiation path along a substrate support path describing a periodic, triangular profile, the substrate support path having a first component generally parallel to the radiation path proximate to the substrate support, the substrate support path having a second component generally perpendicular to the radiation path proximate to the substrate support, the substrate support being movable along both the first and second components of the substrate support path while the reticle moves along the reticle path.